Dual Schmitt-Trigger Inverter

The NL27WZ14 is a high performance dual inverter with Schmitt–Trigger inputs operating from a 2.3 to 5.5 V supply.

Pin configuration and function are the same as the NL27WZ04, but the inputs have hysteresis and, with its Schmitt trigger function, the NL27WZ14 can be used as a line receiver which will receive slow input signals. The NL27WZ14 is capable of transforming slowly changing input signals into sharply defined, jitter–free output signals. In addition, it has a greater noise margin than conventional inverters. The NL27WZ14 has hysteresis between the positive–going and the negative–going input thresholds (typically 1.0 V) which is determined internally by transistor ratios and is essentially insensitive to temperature and supply voltage variations.

- Designed for 2.3 V to 5.5 V V_{CC} Operation
- Over Voltage Tolerant Inputs and Outputs
- LVTTL Compatible Interface Capability with 5 V TTL Logic with $V_{CC} = 3 \text{ V}$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Current Drive Capability is 24 mA at the Outputs
- Chip Complexity: FET = 72

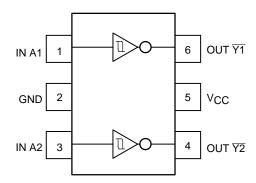


Figure 1. Pinout (Top View)

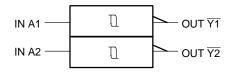


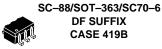
Figure 2. Logic Symbol



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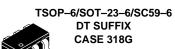






Pin 1

d = Date Code





Pin 1

d = Date Code

PIN ASSIGNMENT

1	IN A1
2	GND
3	IN A2
4	OUT Y2
5	Vcc
6	OUT Y1

FUNCTION TABLE

Y Output
Н
L

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MAXIMUM RATINGS

Symbol	Characteristics	Value	Unit
Vcc	DC Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	$-0.5 \le V_{\parallel} \le +7.0$	V
VO	DC Output Voltage Output in Z or LOW State (Note	1) $-0.5 \le V_{O} \le 7.0$	V
ΙΚ	DC Input Diode Current V _I < Gi	ID -50	mA
lok	DC Output Diode Current V _O < Gi	ID -50	mA
IO	DC Output Sink Current	±50	mA
Icc	DC Supply Current per Supply Pin	±100	mA
IGND	DC Ground Current per Ground Pin	±100	mA
T _{STG}	Storage Temperature Range	-65 to +150	°C
PD	Power Dissipation in Still Air SC–88, TSOP	-6 200	mW
θ JA	Thermal Resistance SC-88, TSOP	-6 333	°C/W
TL	Lead Temperature, 1 mm from case for 10 s	260	°C
TJ	Junction Temperature under Bias	+150	°C
VESD	ESD Withstand Voltage Human Body Model (Note Machine Model (Note Charged Device Model (Note	s) > 200	V

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum–rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. IO absolute maximum rating must be observed.

2. Tested to EIA/JESD22–A114–A

3. Tested to EIA/JESD22–A115–A

- 4. Tested to JESD22-C101-A

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit	
VCC	Supply Voltage	Operating Data Retention Only	2.3 1.5	5.5 5.5	V
VI	Input Voltage		0	5.5	V
VO	Output Voltage	(High or LOW State)	0	5.5	V
TA	Operating Free-Air Temperature		-40	+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$ $V_{CC} = 3.0 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	0 0 0	20 10 5	ns/V

DC ELECTRICAL CHARACTERISTICS

			VCC	TA	= 25°C		-40°C ≤ T	A ≤ 85°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Unit
VT+	Positive Input		2.3	1.0	1.5	1.8	1.0	1.8	V
	Threshold Voltage		2.7	1.2	1.7	2.0	1.2	2.0	1
			3.0	1.3	1.9	2.2	1.3	2.2	1
			4.5	1.9	2.7	3.1	1.9	3.1	1
			5.5	2.2	3.3	3.6	2.2	3.6	1
V _T -	Negative Input		2.3	0.4	0.75	1.15	0.4	1.15	V
	Threshold Voltage		2.7	0.5	0.87	1.4	0.5	1.4	1
			3.0	0.6	1.0	1.5	0.6	1.5	1
			4.5	1.0	1.5	2.0	1.0	2.0	1
			5.5	1.2	1.9	2.3	1.2	2.3	1
V _H Input Hyste	Input Hysteresis Voltage		2.3	0.25	0.75	1.1	1.25	1.1	V
			2.7	0.3	0.83	1.15	0.3	1.15	1
			3.0	0.4	0.93	1.2	0.4	1.2	1
			4.5	0.6	1.2	1.5	0.6	1.5	1
			5.5	0.7	1.4	1.7	0.7	1.7	1
Vон	High-Level Output	I _{OH} = 100 μA	2.3 to 5.5	V _{CC} - 0.1	VCC		V _{CC} - 0.1		V
	Voltage	IOH = -8 mA	2.3	1.9	2.1		1.9		
	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	2.4		2.2]
		$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.7		2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.5		2.3		
		$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.0		3.8]
VOL	Low-Level Output	I _{OL} = 100 μA	2.3 to 5.5			0.1		0.1	V
	Voltage	I _{OL} = 8 mA	2.3		0.2	0.3		0.3	
	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.7		0.22	0.4		0.4]
		I_{OL} = 16 mA	3.0		0.28	0.4		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.38	0.55		0.55	
		$I_{OL} = 32 \text{ mA}$	4.5		0.42	0.55		0.55	
IN	Input Leakage Current	V _{IN} or V _{OUT} = V _{CC} or GND	0 to 5.5			±0.1		±1.0	μΑ
IOFF	Power Off–Output Leakage Current	V _{OUT} = 5.5 V	0			1		10	μА
ICC	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5			1		10	μΑ

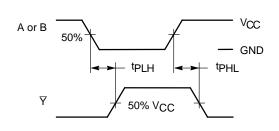
AC ELECTRICAL CHARACTERISTICS (Input $t_f = t_f = 3.0 \text{ ns}$)

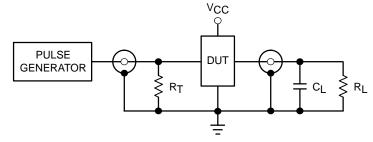
				T _A = 25°C		-40°C ≤				
Symbol	Parameter	Condition	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	
^t PLH	tPLH Propagation Delay Input A to Y (Figure 3 and 4)	$R_L = 1 M\Omega, C_L = 15 pF$	2.5 ± 0.2	1.8	4.3	7.4	1.8	8.1	ns	
^t PHL		•	'	3.3 ± 0.3	1.5	3.3	5.0	1.5	5.5	
		$R_L = 500 \Omega, C_L = 50 pF$		1.8	4.0	6.0	1.8	6.6		
		$R_L = 1 \text{ M}\Omega, C_L = 15 \text{ pF}$	5.0 ± 0.5	1.0	2.7	4.1	1.0	4.5		
		$R_L = 500 \Omega, C_L = 50 pF$		1.2	3.2	4.9	1.2	5.4		

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} =5.5 V, V_I = 0 V or V_{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} 10 MHz, V _{CC} = 5.0 V, V _I = 0 V or V _{CC}	11 12.5	pF

^{5.} CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: ICC(OPR) = CpD • VCC • fin + ICC. CpD is used to determine the no–load dynamic power consumption; PD = CpD • VCC² • fin + ICC • VCC.





 R_T = C_L or equivalent (includes jog and probe capacitance) R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 3. Switching Waveforms

Figure 4. Test Circuit

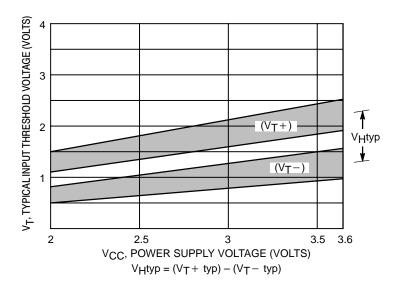
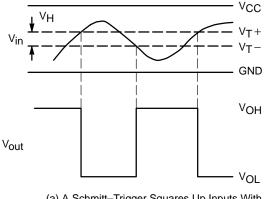
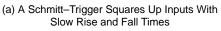
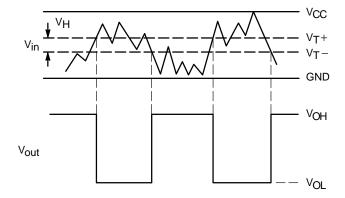


Figure 5. Typical Input Threshold, $v_{T}{\scriptscriptstyle \,+\,}$, $v_{T}{\scriptscriptstyle \,-\,}$ versus Power Supply Voltage







(b) A Schmitt-Trigger Offers Maximum Noise Immunity

Figure 6. Typical Schmitt-Trigger Applications

DEVICE ORDERING INFORMATION

		Device Nomenclature								
Device Order Number	Circuit Indicator	No. of Gates per Package	Temp Range Identifier	Technology	Device Function	Package Suffix	Tape & Reel Suffix	Package Type (Name/SOT#/ Common Name)	Tape and Reel Size	
NL27WZ14DFT2	NL	2	7	WZ	14	DF	T2	SC-88/SOT-363 /SC70-6	178 mm 3000 Units	
NL27WZ14DTT1	NL	2	7	WZ	14	DT	T1	TSOP-6/SOT-23-6 /SC59-6	178 mm 3000 Units	

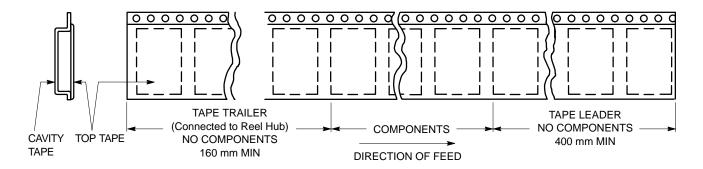


Figure 7. Tape Ends for Finished Goods

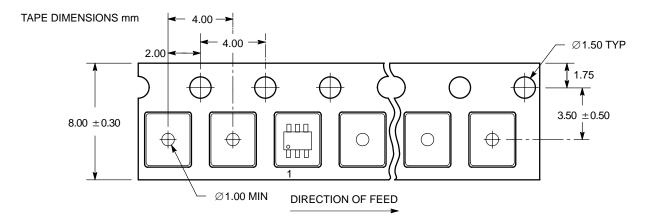


Figure 8. SC70-6/SC-88/SOT-363 DFT2 and SOT23-6/TSOP-6/SC59-6 DTT1 Reel Configuration/Orientation

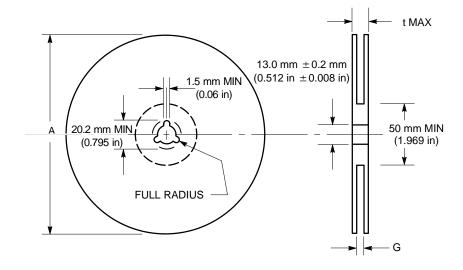


Figure 9. Reel Dimensions

REEL DIMENSIONS

Tape Size	T and R Suffix	A Max	G	t Max
8 mm	T1, T2	178 mm (7 in)	8.4 mm, + 1.5 mm, -0.0 (0.33 in + 0.059 in, -0.00)	14.4 mm (0.56 in)

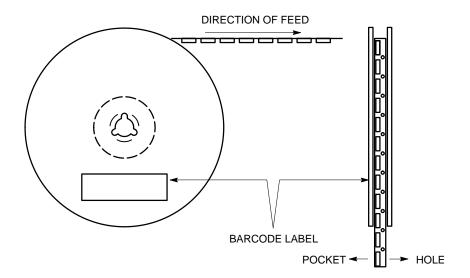
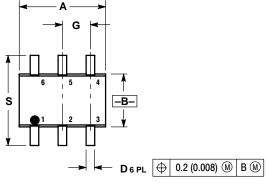


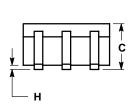
Figure 10. Reel Winding Direction

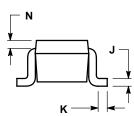
PACKAGE DIMENSIONS

SC70-6/SC-88/SOT-363 **DF SUFFIX**

CASE 419B-02 ISSUE H

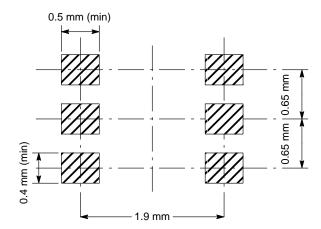






- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

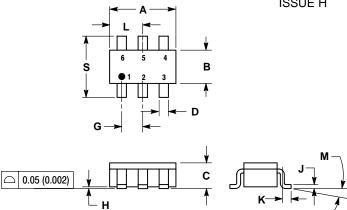
	INC	HES	MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.071	0.087	1.80	2.20	
В	0.045	0.053	1.15	1.35	
С	0.031	0.043	0.80	1.10	
D	0.004	0.012	0.10	0.30	
G	0.026	BSC	0.65 BSC		
Н		0.004		0.10	
J	0.004	0.010	0.10	0.25	
K	0.004	0.012	0.10	0.30	
N	0.008 REF		0.20	REF	
S	0.079	0.087	2.00	2.20	



PACKAGE DIMENSIONS

SOT23-6/TSOP-6/SC59-6 **DT SUFFIX**

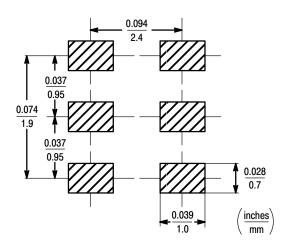
CASE 318G-02 **ISSUE H**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 114.30M, 1902.
 CONTROLLING DIMENSION: MILLIMETER.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD
 FINISH THICKNESS. MINIMUM LEAD THICKNESS
 IS THE MINIMUM THICKNESS OF BASE

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.1142	0.1220
В	1.30	1.70	0.0512	0.0669
С	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.05	0.0335	0.0413
Н	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
M	0 °	10°	0 °	10°
S	2 50	3.00	0.0985	0 1181



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